

### PCN# 20151029000 Qualification of HNT as Additional Assembly and Test Site for Select SOT Package Devices Change Notification / Sample Request

Date: 11/9/2015 To: Newark/Farnell PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (<u>PCN ww admin team@list.ti.com</u>).

Sincerely,

PCN Team SC Business Services

### 20151029000 Attachment: 1

### **Products Affected:**

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

### DEVICE

# CUSTOMER PART NUMBER

ATL431AIDBZR LMR14006XDDCT LMR14006YDDCT null null null

Technical details of this Product Change follow on the next page(s).

PCN	<b>CN Number:</b> 20151029000 <b>PCN Date:</b> 11/9/2015					15						
Title	Qualifica Devices	tion of l	HNT as A	dditi	ional	Assembly	and Test S	Site	for	Select SOT	Package	
Cust	omer Contact	: <u>PC</u>	N Manage	er	Dep	ot:	Quality S	Serv	ice	s		
Prop	osed 1 <sup>st</sup> Ship	Date:	02/9/2	016		Estimated Sample Date Provided at Sample Availability: Date Provided at Sample request		Sample				
Char	Change Type:											
$\square$	Assembly Site				Des	ian				Wafer Bum	p Site	
	Assembly Proc	ess				a Sheet			٦t	Wafer Bum		
	Assembly Mate			$\square$		number c	hange		٦t	Wafer Bum		
	Mechanical Sp		on	$\overline{\boxtimes}$		t Site			٦t	Wafer Fab	•	
$\square$	Packing/Shippi			Ē		t Process			1T	Wafer Fab		
	,								1	Wafer Fab		
					PC	N Detai	ls					
Desc	ription of Cha	nge:										
Test Mate	s Instruments I Site for select o rial differences	levices	listed in									
	Assembly Site	Asse	embly Sit	e Ori	gin	Assembly	Country C	ode		Assembly S	Site City	]
	Weihai		ÁWH		Ŭ	,	CN			Weih		_
Han	a Semiconducto	r	HNT				тн			Ayutth	ava	-
		-			I							J
			ASE We	ihai		Hana Ser	niconducto	)r				
Mou	nt Compound			120999A1		400180		~				
Inica			112000	5711		Т	0100					
	ıp 2 Device:											7
	Assembly Site	Asse	embly Sit	e Ori	gin	Assembly Country Code				Assembly S		_
	1elaka		CU6			MY				Melał		
Han	a Semiconducto	r	HNT				TH			Ayutth	aya	
			TI Mela	ika		Hana Ser	niconducto	or				
Mou	nt Compound		80975	90		400194						
Mole	d Compound		80971	31		450207						
			00011									
Test test I	coverage, inser MQ.	tions, c	ondition	s will	l rem	ain consist	ent with c	urre	ent	testing and	verified v	vith
Reas	son for Chang	e:										
Conti	Continuity of supply.											
Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):												
None												
Anti	cipated impac	t on Ma	aterial D	)ecla	arati	on						
	Anticipated impact on Material Declaration   No Impact to the Material Declarations or Product Content reports are driven from production data and will be available following the production release the revised reports can be obtained from the <u>TI ECO website</u> .											

## Changes to product identification resulting from this PCN:

Assembly Site							
ASE Weihai		Site Origin (22L)	ASO: AWH				
TI Melaka	Assembly S	Site Origin (22L)	ASO: CU6				
Hana Semiconducto	Hana SemiconductorAssembly Site Origin (22L)ASO: HNT						
Sample product shipping label (not actual product label) TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 20: MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04 OPT: ITEM: 39 IRL 5A (I) TO: 1750 (not actual product label) (1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T) LOT: 3959047MLA (4W) TKY (1T) 7523483S12 (P) (2P) REV: (V) 0033317 (20L) CS0: SHE (21L) CC0:USA							
MSL 1 /235C/UNLIM	03/29/04	(4W) TKY (11 (P) (2P) REV: (20L) CSO: SHE	(V) 0033317 (21L) CCO:USA				
MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)T( ASSEMBLY SITE CODI	03/29/04 39 1:1750 ES: ASEWH = I, TIEM =	(4W) TKY(11 (P) (2P) REV: (20L) CSO:SHE (22L) ASO:MLA	r) 7523483SI2				
MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)TO	03/29/04 39 1:1750 ES: ASEWH = I, TIEM =	(4W) TKY(11 (P) (2P) REV: (20L) CSO:SHE (22L) ASO:MLA	(V) 0033317 (21L) CCO:USA				
MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)T( ASSEMBLY SITE CODI Product Affected: G ATL431AIDBZR	03/29/04 39 1750 ES: ASEWH = I, TIEM = roup 1 Devices ATL431AQDBZR	(4W) TKY (11 (P) (2P) REV: (20L) CSO: SHE (22L) ASO: MLA U, HNT = H	<pre>(V) 0033317 (21L) CCO:USA (23L) ACO: MYS</pre>				
MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)T( ASSEMBLY SITE CODI Product Affected: G ATL431AIDBZR	03/29/04 39 1750 ES: ASEWH = I, TIEM = roup 1 Devices ATL431AQDBZR	(4W) TKY (11 (P) (2P) REV: (20L) CSO: SHE (22L) ASO: MLA U, HNT = H	<pre>(V) 0033317 (21L) CCO:USA (23L) ACO: MYS</pre>				
MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)T( ASSEMBLY SITE CODI Product Affected: G ATL431AIDBZR Product Affected: G	03/29/04 39 1750 ES: ASEWH = I, TIEM = roup 1 Devices ATL431AQDBZR roup 2 Devices	(4W) TKY (11 (P) (2P) REV: (20L) CSO: SHE (22L) ASO: MLA U, HNT = H ATL431BIDBZR	T) 7523483SI2 (V) 0033317 (21L) CCO:USA (23L) ACO: MYS ATL431BQDBZR				

# Group 1: Qualification Report HNT SOT-23 DBZ Qualification

### **Product Attributes** QBS Product **QBS** Product Qual Device: Qual Device: Qual Device: Qual Device: Reference: Reference: butes ATL431AIDBZR ATL431BIDBZR ATL432BQDBZR ATL431AQDBZR ATL431BQDBZR ATL431BQDBZR Assembly HANA HANA HANA THAILAND HANA THAILAND ASEWH ASEWH Site THAILAND THAILAND Package SOT SOT SOT SOT SOT SOT Family Flammability UL 94 V-0 Rating Wafer Fab SHE-SHERMAN SHE-SHERMAN SHE-SHERMAN SHE-SHERMAN SFAB SFAB Supplier Wafer JI2 JI2 JI2 JI2 JI2 JI2 Process

Attributes	QBS Product Reference:	QBS Process Reference:	QBS Process Reference:	QBS Package Reference:	QBS Package Reference:
	TL431BIP	TL1431CDR	TL4242TDRJRQ1	TLV431AIDBZ6	TLV431BCDBZR
Assembly Site	MEX	MLA	MLA	HANA	HANA
Package Family	PDIP	SOIC	QFN	SOT	SOT

Flammability Rating	UL 94 V0	UL 94 V-0	UL 94 V-0	UL 94 V 0	UL 94 V0
Wafer Fab Supplier	SFAB	SFAB	SFAB	HIJ	SFAB
Wafer Process	JI Bipolar	JI BIPOLAR	JI2	OI BIPOLAR	JI Bipolar

- QBS: Qual By Similarity

- Qual Devices qualified at LEVEL1-260CG: ATL431AIDBZR, ATL431AQDBZR, ATL431BIDBZR, ATL431BQDBZR, ATL431BIDBZR, ATL431BQDBZR, ATL431AQDBZR, and ATL431AIDBZR

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

	Data Displayed as: Number of lots / Total sample size / Total failed							
Туре	Test Name /	Duration	Qual Device:	Qual Device:	Qual Device:	Qual Device:	QBS Product Reference:	
Type	Condition		ATL431AIDBZ R	ATL431AQDBZ R	ATL431BIDBZ R	ATL431BQDBZ R	ATL431BQDBZ R	
AC	Autoclave 121C	96 Hours	-	-	-	-	-	
ED	Electrical Characterization	Per Datasheet Paramete rs	Pass	Pass	Pass	Pass	Pass	
ELF R	Early Life Failure Rate, 150C	48 Hours	-	-	-	-	-	
FLA M	Flammability (IEC 695-2-2)		-	-	-	-	-	
FLA M	Flammability (UL 94V-0)		-	-	-	-	-	
FLA M	Flammability (UL- 1694)		-	-	-	-	-	
HAS T	Biased HAST, 130C/85%RH	96 Hours	-	-	-	-	-	
HBM	ESD - HBM	2000 V	-	-	-	-	1/3/2000	
CDM	ESD - CDM	1500 V	-	-	-	-	1/3/2000	
HTO L	Life Test, 150C	300 Hours	-	-	-	-	1/77/0	
HTS L	High Temp. Storage Bake, 175C	500 Hours	-	-	-	-	-	
HTS L	High Temp. Storage Bake, 150C	1000 Hours	-	-	-	-	-	
LI	Lead Integrity	Leads	-	-	-	-	-	
LI	Lead Pull	Leads	-	-	-	-	-	
LU	Latch-up	(per JESD78)	-	-	-	-	1/6/2000	
PD	Physical Dimensions		-	-	-	-	-	
SD	Surface Mount Solderability	8 Hours Steam Age	-	-	-	-	-	
SD	Surface Mount Solderability	Pb Free	-	-	-	-	-	
тс	Temperature Cycle, -65/150C	500 Cycles	-	-	-	-	-	
TS	Thermal Shock - 65/150C	500 Cycles	-	-	-	-	-	

Туре	Test Name / Condition	Duration	QBS Product Reference:	QBS Product Reference:	QBS Process Reference:	QBS Process Reference:	QBS Package Reference:	QBS Package Reference:
	Condition		ATL432BQDBZ R	TL431BIP	TL1431CDR	TL4242TDRJR Q1	TLV431AIDBZ 6	TLV431BCDBZ R
AC	Autoclave 121C	96 Hours	-	1/77/0	-	3/231/0	3/231/0	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	Pass	-	-	-	-	-
ELFR	Early Life Failure Rate, 150C	48 Hours	-	-	3/2400/0	-	-	-
FLAM	Flammability (IEC 695-2-2)		-	-	-	-	3/15/2000	-
FLAM	Flammability (UL 94V-0)		-	-	-	-	3/15/2000	-
FLAM	Flammability (UL-1694)		-	-	-	-	3/15/2000	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	1/77/0	-	3/231/0	3/231/0	3/78/0
HBM	ESD - HBM	2000 V	-	-	-	-	-	-
CDM	ESD - CDM	1500 V	1/3/2000	-	-	-	-	-
HTOL	Life Test, 150C	300 Hours	-	1/77/0	-	3/231/0	3/231/0	3/150/0
HTSL	High Temp. Storage Bake, 175C	500 Hours	-	-	-	1/45/0	-	-
HTSL	High Temp. Storage Bake, 150C	1000 Hours	-	-	-	-	3/135/0	3/230/0
LI	Lead Integrity	Leads	-	-	-	-	3/66/0	-
LI	Lead Pull	Leads	-	-	-	-	3/66/0	-
LU	Latch-up	(per JESD78)	1/6/2000	-	-	1/6/2000	-	-
PD	Physical Dimensions		-	-	-	-	3/15/2000	-
SD	Surface Mount Solderability	8 Hours Steam Age	-	-	-	1/15/2000	3/66/0	-
SD	Surface Mount Solderability	Pb Free	-	-	-	1/15/2000	-	-
тс	Temperature Cycle, -65/150C	500 Cycles	-	1/77/0	-	3/231/0	1/77/0	3/230/0
TS	Thermal Shock -65/150C	500 Cycles	-	-	-	-	3/230/0	-

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

## Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

# **Group 2: Qualification Report** LV2842XLVDDC Hana – Thailand

LV2842XLVDDC Hana – Thailand

# **Product Attributes**

Attributes	Qual Device: LV2842XLVDDCR
Assembly Site	HNT
Package Family	TSOT COL
Flammability Rating	UL 94 V-0
Wafer Fab Supplier	DM0S5
Wafer Fab Process	LBC5

- Qual Device LV2842XLVDDCR is qualified at LEVEL1-260C

# **Qualification Results**

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition Duration		Qual Device: LV2842XLVDDCR
HAST	Unbiased HAST,130C/85%RH	96 hours	3/231/0
ED	Electrical Characterization	-	Pass
BHAST	Biased HAST, 130C/85%RH	96 hours	3/231/0
PC	Preconditioning	Level 1 @ 260C	3/693/0
TC	T/C -65C/150C	500 cycles	3/231/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

### Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com